

# TPS22917x 1 V–5.5-V, 2-A, 80-mΩ Ultra-Low Leakage Load Switch

## 1 Features

- Input operating voltage range ( $V_{IN}$ ): 1 V to 5.5 V
- Maximum continuous current ( $I_{MAX}$ ): 2 A
- On-resistance ( $R_{ON}$ ):
  - 5  $V_{IN}$  = 80 mΩ (typical)
  - 1.8  $V_{IN}$  = 120 mΩ (typical)
  - 1  $V_{IN}$  = 220 mΩ (typical)
- Ultra-low power consumption:
  - ON state ( $I_Q$ ): 0.5  $\mu$ A (typical)
  - OFF state ( $I_{SD}$ ): 10 nA (typical)
- Smart ON pin pulldown ( $R_{PD}$ ):
  - ON  $\geq V_{IH}$  ( $I_{ON}$ ): 10 nA (maximum)
  - ON  $\leq V_{IL}$  ( $R_{PD}$ ): 750 kΩ (typical)
- Adjustable turn ON limits inrush current ( $t_{ON}$ ):
  - 5-V  $t_{ON}$  = 100  $\mu$ s at 72 mV/ $\mu$ s ( $C_T$  = open)
  - 5-V  $t_{ON}$  = 4000  $\mu$ s at 2.3 mV/ $\mu$ s ( $C_T$  = 1000 pF)
- Adjustable output discharge and fall time:
  - Optional QOD resistance  $\geq 150 \Omega$  (internal)
- Always-ON true Reverse Current Blocking (RCB):
  - Activation current ( $I_{RCB}$ ): –500 mA (typical)
  - Reverse leakage ( $I_{IN,RCB}$ ): –1  $\mu$ A (maximum)

## 2 Applications

- Industrial systems
- Set top box
- Blood glucose meters
- Electronic point of sale

## 3 Description

The TPS22917x device is a small, single channel load switch using a low leakage P-Channel MOSFET for minimum power loss. Advanced gate control design supports operating voltages as low as 1 V with minimal increase in ON-Resistance and power loss.

The Rise and Fall times can be independently adjusted with external components for system level optimizations. The timing capacitor ( $C_T$ ) and turn on time can be adjusted to manage inrush current without adding unnecessary system delays. The output discharge resistance (QOD) can be used to adjust the output fall time. Connect the QOD pin directly to the output for a fastest fall time or leave it open for the slowest fall time.

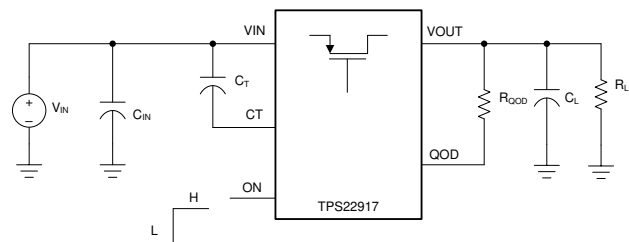
The switch ON state is controlled by a digital input that can interface directly with low-voltage control signals. The TPS22917 uses active high enable logic, while the TPS22917L uses active low. When power is first applied, a Smart Pulldown is used to keep the ON pin from floating until system sequencing is complete. After the ON pin is deliberately driven high ( $\geq V_{IH}$ ), the Smart Pulldown ( $R_{PD}$ ) is disconnected to prevent unnecessary power loss.

The TPS22917x device is available in a leaded SOT-23 package (DBV) which allows visual inspection of solder joints. The device is characterized for operation over a temperature range of –40°C to 125°C.

### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS22917x	SOT-23 (6)	2.90 mm × 1.60 mm

- (1) For all available packages, see the orderable addendum at the end of the data sheet.



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### Simplified Schematic



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

<b>Changes from Revision A (February 2018) to Revision B (December 2021)</b>	<b>Page</b>
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Added TPS22917L orderable to the data sheet.....	1

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<b>Changes from Revision * (September 2017) to Revision A (February 2018)</b>	<b>Page</b>
• Changed product status from Advanced Information to Production Data .....	1

## 5 Device Comparison Table

Device	ON Pin Logic
TPS22917	Active High
TPS22917L	Active Low

## 6 Pin Configuration and Functions



Figure 6-1. DBV Package 6-Pin SOT-23 Top View

Table 6-1. Pin Functions

PIN		I/O	DESCRIPTION
NO.	NAME		
1	VIN	I	Switch input
2	GND	—	Device ground
3	ON	I	Active high switch control input. Do not leave floating.
4	CT	O	Switch slew rate control. Connect capacitor from this pin to VIN to increase output slew rate and turn-on time. Can be left floating for fastest timing.
5	QOD	O	Quick Output Discharge pin. This functionality can be enabled in one of three ways. <ul style="list-style-type: none"> <li>Placing an external resistor between VOUT and QOD</li> <li>Tying QOD directly to VOUT and using the internal resistor value (<math>R_{PD}</math>)</li> <li>Disabling QOD by leaving pin floating</li> </ul> See the <a href="#">Fall Time (<math>t_{FALL}</math>) and Quick Output Discharge (QOD)</a> section for more information.
6	VOUT	O	Switch output

## 7 Specifications

### 7.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
V <sub>IN</sub>	Input voltage	-0.3	6	V
V <sub>OUT</sub>	Output voltage	-0.3	6	V
V <sub>ON</sub>	Enable voltage	-0.3	6	V
V <sub>QOD</sub>	QOD pin voltage	-0.3	6	V
I <sub>MAX</sub>	Maximum continuous switch current		2	A
I <sub>PLS</sub>	Maximum pulsed switch current, pulse < 300-μs, 2% duty cycle		2.5	A
T <sub>J,MAX</sub>	Maximum junction temperature		125	°C
T <sub>STG</sub>	Storage temperature	-65	150	°C
T <sub>LEAD</sub>	Maximum Lead temperature (10-s soldering time)		300	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 7.2 ESD Ratings

		VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions. Pins listed as ±2000 V may actually have higher performance.  
 (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions. Pins listed as ±500 V may actually have higher performance.

### 7.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V <sub>IN</sub>	Input voltage	1	5.5	V
V <sub>OUT</sub>	Output voltage	0	5.5	V
V <sub>IH</sub>	High-level input voltage, ON	1	5.5	V
V <sub>IL</sub>	Low-level input voltage, ON	0	0.35	V
V <sub>QOD</sub>	QOD Pin Voltage	0	5.5	V
V <sub>CT</sub>	Timing Capacitor Voltage Rating	7		V

### 7.4 Thermal Information

Thermal Parameters <sup>(1)</sup>	TPS22917	UNIT	
	DBV (SOT-23)		
	6 PINS		
θ <sub>JA</sub>	Junction-to-ambient thermal resistance	183	°C/W
θ <sub>JCTop</sub>	Junction-to-case (top) thermal resistance	152	°C/W
θ <sub>JB</sub>	Junction-to-board thermal resistance	34	°C/W
ψ <sub>JT</sub>	Junction-to-top characterization parameter	37	°C/W
ψ <sub>JB</sub>	Junction-to-board characterization parameter	33	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 7.5 Electrical Characteristics

Unless otherwise noted, the specification in the following table applies for all variants over the entire recommended power supply voltage range of 1 V to 5.5 V. Typical Values are at 25°C.

PARAMETER		TEST CONDITIONS	T <sub>J</sub>	MIN	TYP	MAX	UNIT	
<b>INPUT SUPPLY(V<sub>IN</sub>)</b>								
I <sub>Q,VIN</sub>	V <sub>IN</sub> Quiescent current	Enabled, V <sub>OUT</sub> = Open	-40°C to +85°C	0.5	1.0		μA	
			-40°C to +125°C			1.2	μA	
I <sub>SD,VIN</sub>	V <sub>IN</sub> Shutdown current	Disabled, V <sub>OUT</sub> = GND (TPS22917)	-40°C to +85°C	10	100		nA	
			-40°C to +105°C			250	nA	
		Disabled, V <sub>OUT</sub> = GND (TPS22917L)	-40°C to +85°C	175	300		nA	
			-40°C to +105°C			400	nA	
<b>ON-RESISTANCE(R<sub>ON</sub>)</b>								
R <sub>ON</sub>	ON-Resistance	I <sub>OUT</sub> = 200 mA	V <sub>IN</sub> = 5 V	25°C	80	100	mΩ	
				-40°C to +85°C				120
				-40°C to +105°C				130
				-40°C to +125°C				140
			V <sub>IN</sub> = 3.6 V	25°C	90	110		
				-40°C to +85°C				140
				-40°C to +105°C				150
				-40°C to +125°C				160
			V <sub>IN</sub> = 1.8 V	25°C	120	150		
				-40°C to +85°C				175
				-40°C to +105°C				185
				-40°C to +125°C				200
			V <sub>IN</sub> = 1.2 V	25°C	170	220		
				-40°C to +85°C				265
				-40°C to +105°C				280
				-40°C to +125°C				300
			V <sub>IN</sub> = 1.0 V	25°C	220	300		
				-40°C to +85°C				350
				-40°C to +105°C				370
				-40°C to +125°C				390
<b>ENABLE PIN(ON)</b>								
I <sub>ON</sub>	ON Pin leakage	Enabled (TPS22917)	-40°C to +125°C	-10	10		nA	
		Enabled (TPS22917L)	-40°C to +125°C	-20	20		nA	
R <sub>PD</sub>	Smart Pull Down Resistance	V <sub>ON</sub> ≤ V <sub>IL</sub>	-40°C to +105°C		750		kΩ	
<b>REVERSE CURRENT BLOCKING(RCB)</b>								
I <sub>RCB</sub>	RCB Activation Current	Enabled, V <sub>OUT</sub> > V <sub>IN</sub>	-40°C to +125°C	-0.5	-1		A	
t <sub>RCB</sub>	RCB Activation time	Enabled, V <sub>OUT</sub> > V <sub>IN</sub> + 200mV	-40°C to +125°C		10		μs	
V <sub>RCB</sub>	RCB Release Voltage	Enabled, V <sub>OUT</sub> > V <sub>IN</sub>	-40°C to +125°C		25		mV	
I <sub>IN,RCB</sub>	V <sub>IN</sub> Reverse Leakage Current	0 V ≤ V <sub>IN</sub> + V <sub>RCB</sub> ≤ V <sub>OUT</sub> ≤ 5.5 V	-40°C to +105°C	-1			μA	
<b>QUICK OUTPUT DISCHARGE(QOD)</b>								
QOD	Output discharge resistance	Disabled	-40°C to +105°C		150		Ω	

## 7.6 Switching Characteristics

Unless otherwise noted, the typical characteristics in the following table applies over the entire recommended power supply voltage range of 1 V to 5.5 V at 25°C with a load of  $C_L = 1 \mu\text{F}$ ,  $R_L = 10 \Omega$

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
$t_{\text{ON}}$	Turn ON Time	$V_{\text{IN}} = 5.0 \text{ V}$	$C_T = \text{Open}$		100		$\mu\text{s}$
			$C_T \geq 100 \text{ pF}$		4		$\mu\text{s/pF}$
		$V_{\text{IN}} = 3.6 \text{ V}$	$C_T = \text{Open}$		120		$\mu\text{s}$
			$C_T \geq 100 \text{ pF}$		3.8		$\mu\text{s/pF}$
		$V_{\text{IN}} = 1.8 \text{ V}$	$C_T = \text{Open}$		200		$\mu\text{s}$
			$C_T \geq 100 \text{ pF}$		3.6		$\mu\text{s/pF}$
		$V_{\text{IN}} = 1.2 \text{ V}$	$C_T = \text{Open}$		300		$\mu\text{s}$
			$C_T \geq 200 \text{ pF}$		3.4		$\mu\text{s/pF}$
		$V_{\text{IN}} = 1.0 \text{ V}$	$C_T = \text{Open}$		400		$\mu\text{s}$
			$C_T \geq 400 \text{ pF}$		3		$\mu\text{s/pF}$
$t_{\text{R}}$	Output Rise Time	$V_{\text{IN}} = 5.0 \text{ V}$	$C_T = \text{Open}$		55		$\mu\text{s}$
			$C_T \geq 100 \text{ pF}$		1.8		$\mu\text{s/pF}$
		$V_{\text{IN}} = 3.6 \text{ V}$	$C_T = \text{Open}$		65		$\mu\text{s}$
			$C_T \geq 100 \text{ pF}$		1.6		$\mu\text{s/pF}$
		$V_{\text{IN}} = 1.8 \text{ V}$	$C_T = \text{Open}$		100		$\mu\text{s}$
			$C_T \geq 100 \text{ pF}$		1.2		$\mu\text{s/pF}$
		$V_{\text{IN}} = 1.2 \text{ V}$	$C_T = \text{Open}$		150		$\mu\text{s}$
			$C_T \geq 200 \text{ pF}$		0.95		$\mu\text{s/pF}$
		$V_{\text{IN}} = 1.0 \text{ V}$	$C_T = \text{Open}$		200		$\mu\text{s}$
			$C_T \geq 400 \text{ pF}$		0.6		$\mu\text{s/pF}$
$SR_{\text{ON}}$	Turn ON Slew Rate <sup>(1)</sup>	$V_{\text{IN}} = 5.0 \text{ V}$	$C_T = \text{Open}$		72		$\text{mV}/\mu\text{s}$
			$C_T \geq 100 \text{ pF}$		2300		$(\text{mV}/\mu\text{s}) * \text{pF}$
		$V_{\text{IN}} = 3.6 \text{ V}$	$C_T = \text{Open}$		44		$\text{mV}/\mu\text{s}$
			$C_T \geq 100 \text{ pF}$		1900		$(\text{mV}/\mu\text{s}) * \text{pF}$
		$V_{\text{IN}} = 1.8 \text{ V}$	$C_T = \text{Open}$		14		$\text{mV}/\mu\text{s}$
			$C_T \geq 100 \text{ pF}$		1100		$(\text{mV}/\mu\text{s}) * \text{pF}$
		$V_{\text{IN}} = 1.2 \text{ V}$	$C_T = \text{Open}$		6.2		$\text{mV}/\mu\text{s}$
			$C_T \geq 200 \text{ pF}$		1000		$(\text{mV}/\mu\text{s}) * \text{pF}$
		$V_{\text{IN}} = 1.0 \text{ V}$	$C_T = \text{Open}$		3.9		$\text{mV}/\mu\text{s}$
			$C_T \geq 400 \text{ pF}$		1100		$(\text{mV}/\mu\text{s}) * \text{pF}$
$t_{\text{OFF}}$	Turn OFF Time				10		$\mu\text{s}$
$t_{\text{FALL}}$	Output Fall Time <sup>(2)</sup>	$R_L = 10 \Omega$	$C_L = 1\mu\text{F}, R_{\text{QOD}} = \text{Short}$		22		$\mu\text{s}$
			$C_L = 10\mu\text{F}, R_{\text{QOD}} = \text{Short}$		3.8		ms
		$R_L = \text{Open}$	$C_L = 10\mu\text{F}, R_{\text{QOD}} = 100 \Omega$		5.9		ms
			$C_L = 220\mu\text{F}, R_{\text{QOD}} = \text{Short}$		72		ms

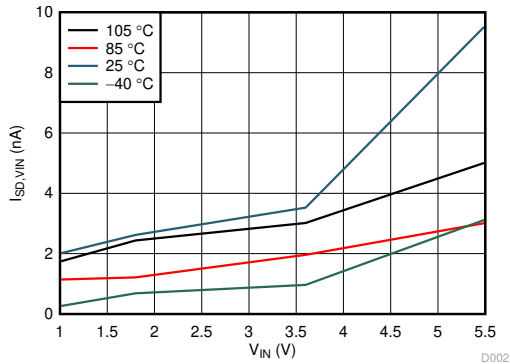
(1)  $SR_{\text{ON}}$  is the fastest Slew Rate during the turn on time ( $t_{\text{ON}}$ )

(2) Output may not discharge completely if QOD is not connected to VOUT.

## 7.7 Typical Characteristics

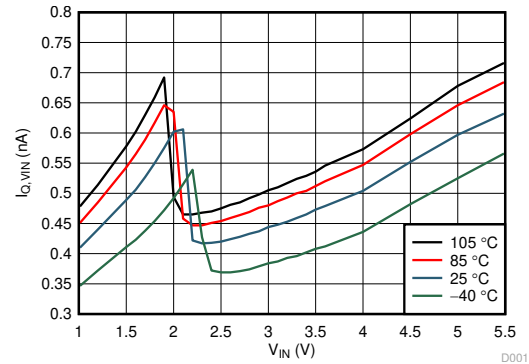
### 7.7.1 Typical Electrical Characteristics

The typical characteristics curves in this section apply at 25°C unless otherwise noted.



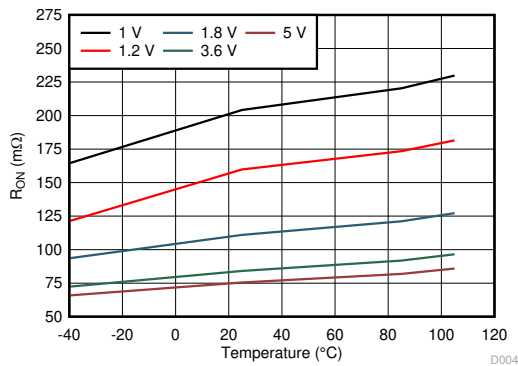
$$V_{ON} \leq V_{IL}$$

Figure 7-1. Shutdown Current ( $I_{SD}$ )



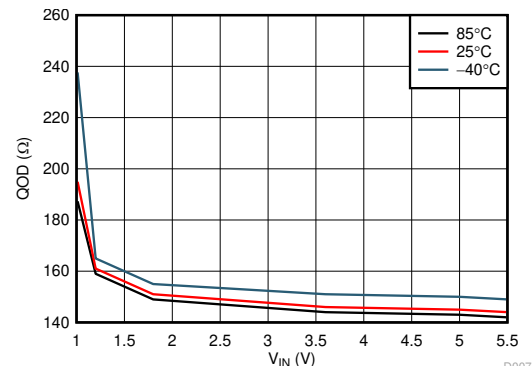
$$V_{ON} \geq V_{IH}$$

Figure 7-2. Quiescent Current ( $I_Q$ )



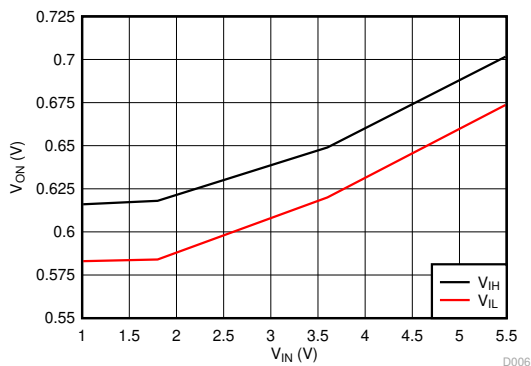
$$V_{ON} \geq V_{IH}$$

Figure 7-3. ON-Resistance ( $R_{ON}$ )



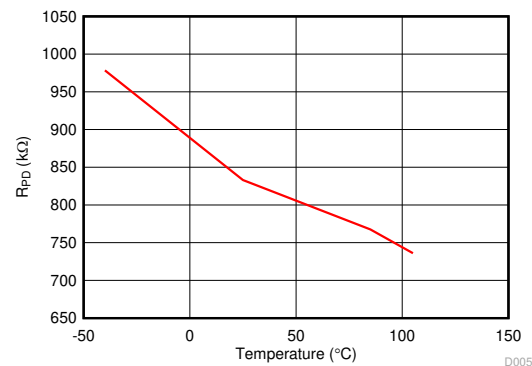
$$V_{ON} \leq V_{IL}$$

Figure 7-4. Quick Output Discharge (QOD)



-40°C to +105°C

Figure 7-5. ON Pin Threshold



$$V_{ON} \leq V_{IL}$$

Figure 7-6. ON Pin Smart Pulldown ( $R_{PD}$ )

### 7.7.2 Typical Switching Characteristics

The typical data in this section apply at 25°C with a load of  $C_L = 1 \mu\text{F}$ ,  $R_L = 10 \Omega$ , and QOD shorted to VOUT unless otherwise noted.



Figure 7-7. Turn-On Time (CT = Open)

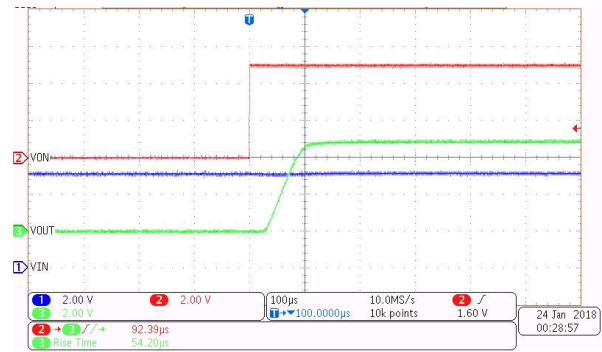


Figure 7-8. Turn-On at 5 V (CT = Open)

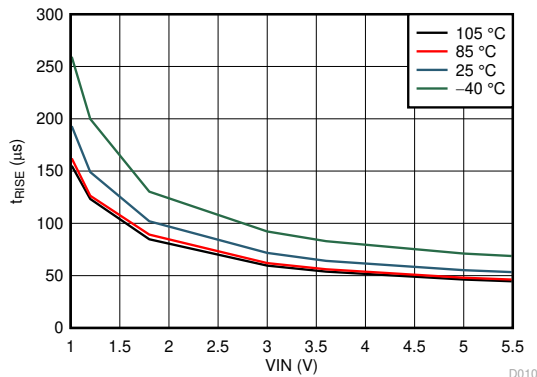


Figure 7-9. Rise Time (CT = Open)

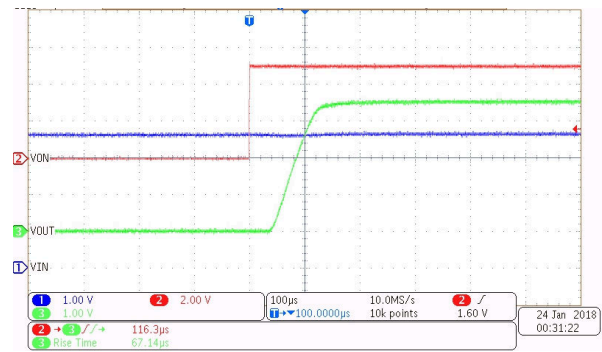


Figure 7-10. Turn-On at 3.6 V (CT = Open)

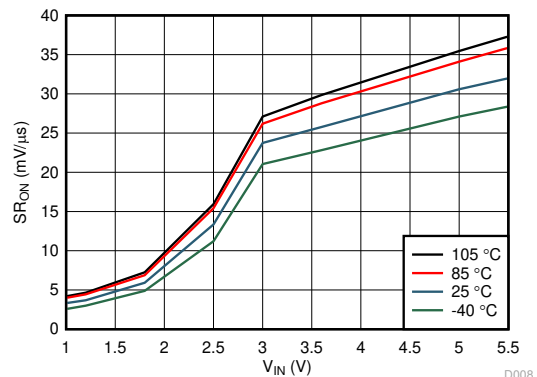


Figure 7-11. Slew Rate (CT = Open)

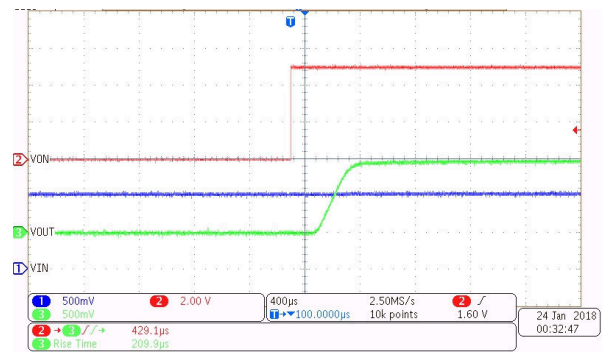


Figure 7-12. Turn On at 1 V (CT = Open)

7.7.2 Typical Switching Characteristics (continued)

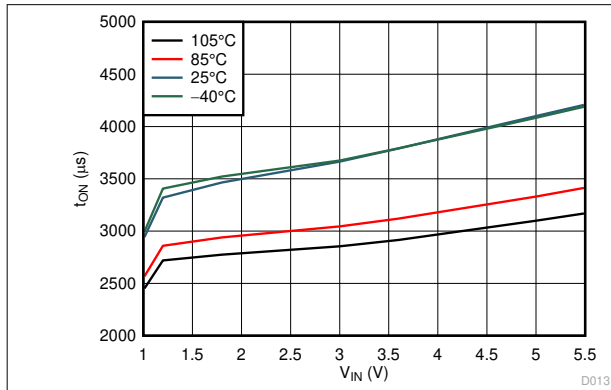


Figure 7-13. Turn On Time (CT = 1000 pF)



Figure 7-14. Turn-On at 5 V (CT = 1000 pF)

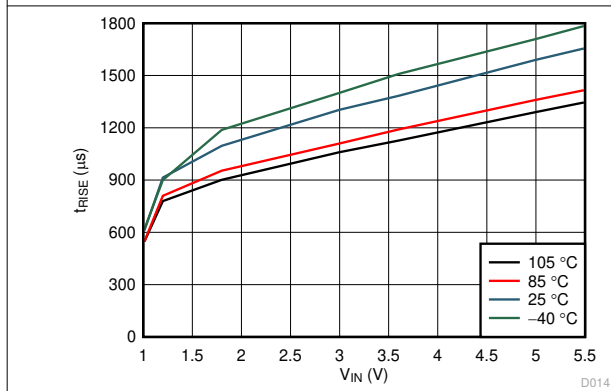


Figure 7-15. Rise Time (CT = 1000 pF)

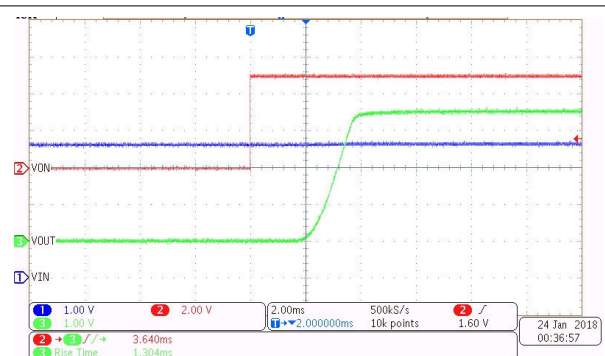


Figure 7-16. Turn-On at 3.6 V (CT = 1000 pF)

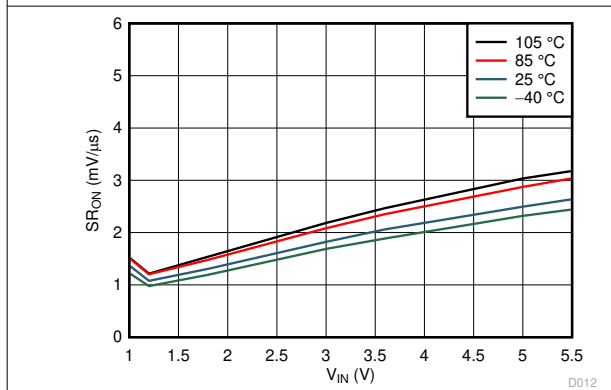


Figure 7-17. Slow Slew Rate (CT = 1000 pF)

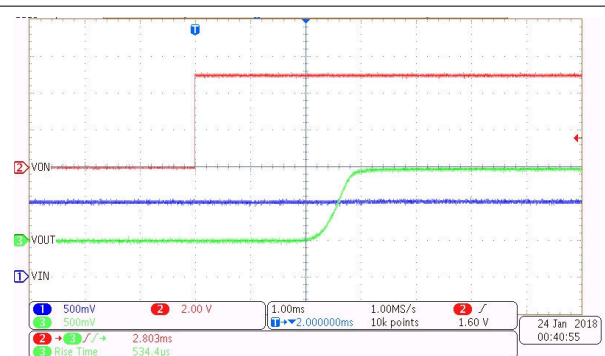


Figure 7-18. Turn-On at 1 V (CT = 1000 pF)

### 7.7.2 Typical Switching Characteristics (continued)

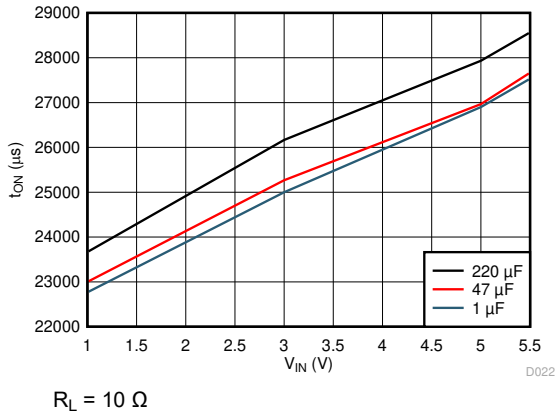


Figure 7-19. Turn-On vs Load Capacitance (CT = 10000 pF)

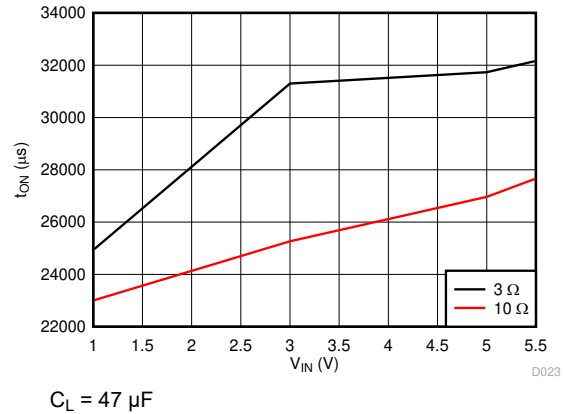


Figure 7-20. Turn-On vs Load Resistance (CT = 10000 pF)

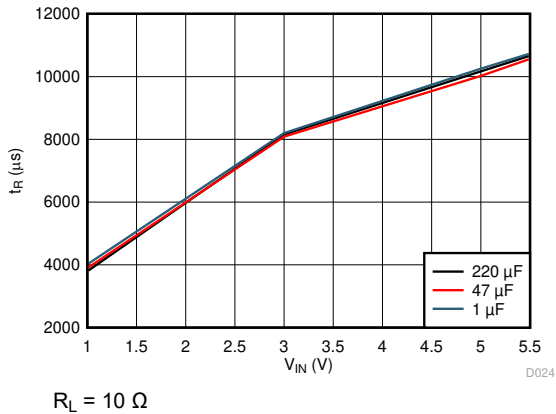


Figure 7-21. Rise Time vs Load Capacitance (CT = 10000 pF)

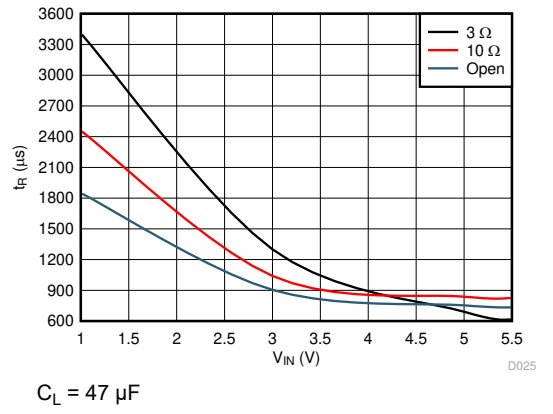


Figure 7-22. Rise Time vs Load Resistance (CT = 10000 pF)

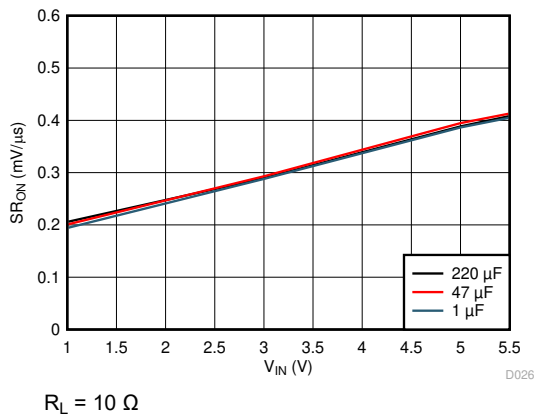


Figure 7-23. Slew Rate vs Load Capacitance (CT = 10000 pF)

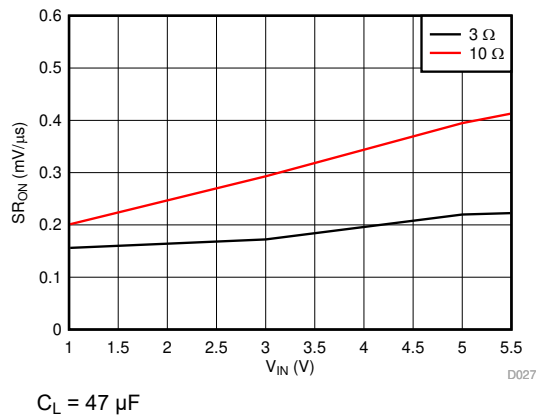


Figure 7-24. Slew Rate vs Load Resistance (CT = 10000 pF)

7.7.2 Typical Switching Characteristics (continued)

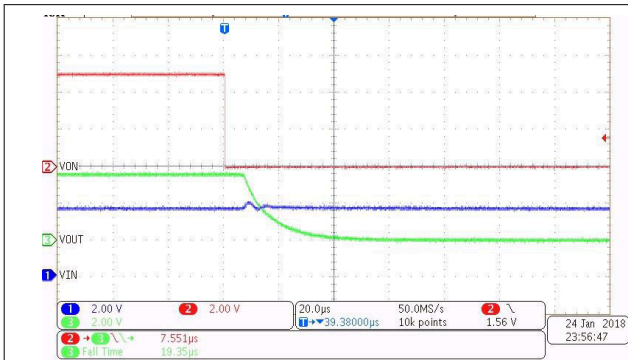
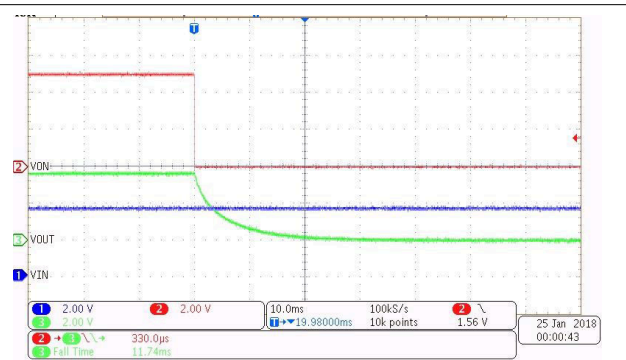


Figure 7-25. Turn-Off at 3.6 V



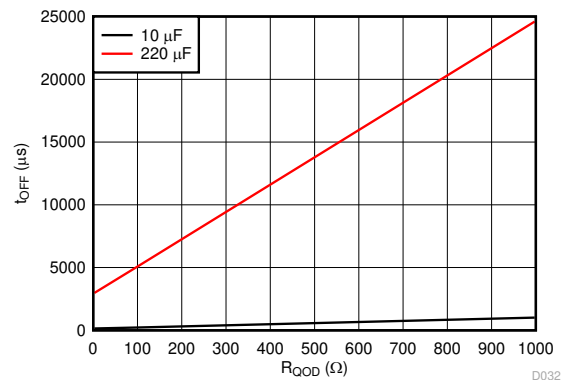
$R_L = \text{Open}$        $C_L = 47 \mu\text{F}$

Figure 7-26. Turn-Off at 3.6 V (Open Load)



$V_{IN} = 1 \text{ V to } 5.5 \text{ V}$

Figure 7-27. Turn-Off Time



$V_{IN} = 1 \text{ V to } 5.5 \text{ V}$

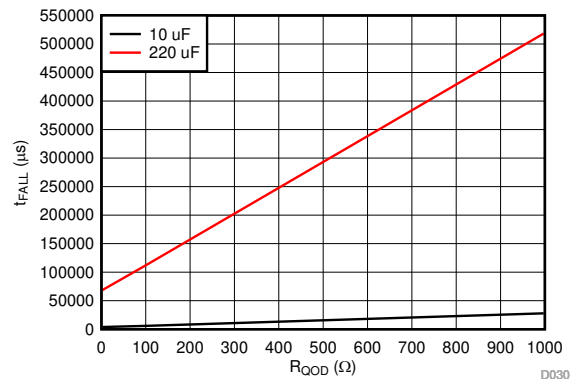
$R_L = \text{Open}$

Figure 7-28. Turn-Off Time (Open Load)



$V_{IN} = 1 \text{ V to } 5.5 \text{ V}$

Figure 7-29. Fall Time

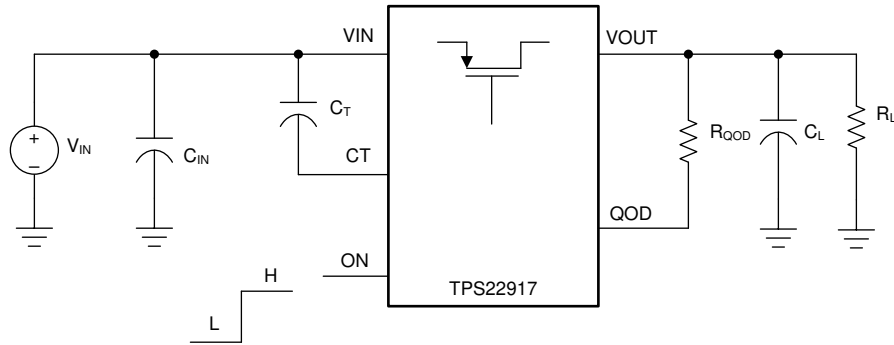


$V_{IN} = 1 \text{ V to } 5.5 \text{ V}$        $R_L = \text{Open}$

Figure 7-30. Fall Time (Open Load)

## 8 Parameter Measurement Information

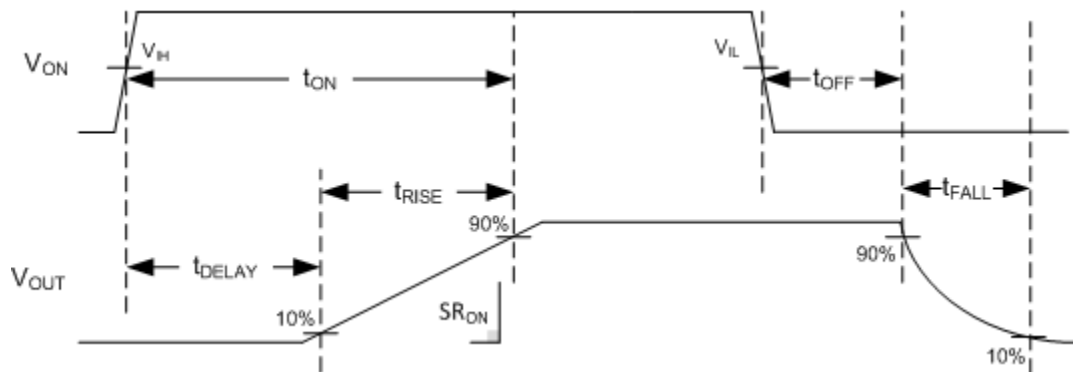
### 8.1 Test Circuit and Timing Waveforms Diagrams



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- A. Rise and fall times of the control signal are 100 ns.
- B. Turn-off times and fall times are dependent on the time constant at the load. For TPS22917x, the internal pull-down resistance QOD is enabled when the switch is disabled. The time constant is  $(R_{QOD} + QOD \parallel R_L) \times C_L$ .

**Figure 8-1. Test Circuit**



**Figure 8-2. Timing Waveforms**

## 9 Detailed Description

### 9.1 Overview

The TPS22917x device is a 5.5-V, 2-A load switch in a 6-pin SOT-23 package. To reduce voltage drop for low voltage and high current rails, the device implements a low resistance P-channel MOSFET which reduces the drop out voltage across the device.

The TPS22917x device has a configurable slew rate which helps reduce or eliminate power supply droop because of large inrush currents. Furthermore, the device features a QOD pin, which allows the configuration of the discharge rate of VOUT after the switch is disabled. During shutdown, the device has very low leakage currents, thereby reducing unnecessary leakages for downstream modules during standby. Integrated control logic, driver, charge pump, and output discharge FET eliminates the need for any external components which reduces solution size and bill of materials (BOM) count.

### 9.2 Functional Block Diagram



## 9.3 Feature Description

### 9.3.1 On and Off Control

The ON pin controls the state of the switch. The ON pin is compatible with standard GPIO logic threshold so it can be used in a wide variety of applications. The TPS22917 is enabled when the voltage applied to the ON pin is pulled above  $V_{IH}$ , while the TPS22917L is enabled when the voltage is below  $V_{IL}$ .

When power is first applied to VIN, a Smart Pulldown is used to keep the ON pin from floating until system sequencing is complete. After the ON pin is deliberately driven high ( $\geq V_{IH}$ ), the Smart Pulldown is disconnected to prevent unnecessary power loss. [Table 9-1](#) shown then the ON Pin Smart Pulldown is active.

**Table 9-1. Smart-ON Pulldown**

VON	Pulldown
$\leq V_{IL}$	Connected
$\geq V_{IH}$	Disconnected

### 9.3.2 Turn-On Time ( $t_{ON}$ ) and Adjustable Slew Rate (CT)

A capacitor to VIN on the CT pin sets the slew rate of  $V_{OUT}$ . The CT capacitor voltage ramps until shortly after the switch is turned on and  $V_{OUT}$  becomes stable.

Leaving the CT pin open results in the highest slew rate and fastest turn-on time. These values can be found in the Switching Characteristics Table. For slower slew rates the required CT capacitor can be found using [Equation 1](#):

$$CT = (\text{Slew Rate}) \div SR_{ON} \quad (1)$$

where

- Slew Rate = desired slew rate (mV/us)
- CT = the capacitance value on the CT pin (pF)
- $SR_{ON}$  = slew rate constant from table [(mV/ $\mu$ s)  $\times$  pF]

The total turn-on time has a direct correlation to the output slew rate. The fastest turn on times ( $t_{ON}$ ), with CT pin open, can be found in the [Switching Characteristics](#). For slower slew rates, the resulting turn-on time can be found with [Equation 2](#):

$$\text{Turn-On time} = CT \times t_{ON} \quad (2)$$

where

- Turn-On Time = total time from enable until  $V_{OUT}$  rises to 90% of  $V_{IN}$  ( $\mu$ s)
- CT = the capacitance value on the CT pin (pF)
- $t_{ON}$  = Turn-On time constant ( $\mu$ s/pF)

### 9.3.3 Fall Time ( $t_{FALL}$ ) and Quick Output Discharge (QOD)

The TPS22917x device includes a QOD pin that can be configured in one of three ways:

- QOD pin shorted to VOUT pin. Using this method, the discharge rate after the switch becomes disabled is controlled with the value of the internal resistance QOD.
- QOD pin connected to VOUT pin using an external resistor  $R_{QOD}$ . After the switch becomes disabled, the discharge rate is controlled by the value of the total discharge resistance. To adjust the total discharge resistance, [Equation 3](#) can be used:

$$R_{DIS} = QOD + R_{QOD} \quad (3)$$

– Where:

- $R_{DIS}$  = total output discharge resistance ( $\Omega$ )
- QOD = internal pulldown resistance ( $\Omega$ )
- $R_{QOD}$  = external resistance placed between the VOUT and QOD pins ( $\Omega$ )

- QOD pin is unused and left floating. Using this method, there is no quick output discharge functionality, and the output remains floating after the switch is disabled.

The fall times of the device depend on many factors including the total discharge resistance ( $R_{DIS}$ ) and the output capacitance ( $C_L$ ). To calculate the approximate fall time of  $V_{OUT}$  use [Equation 4](#).

$$t_{FALL} = 2.2 \times (R_{DIS} \parallel R_L) \times C_L \quad (4)$$

Where:

- $t_{FALL}$  = output fall time from 90% to 10% ( $\mu s$ )
- $R_{DIS}$  = total QOD +  $R_{QOD}$  resistance ( $\Omega$ )
- $R_L$  = output load resistance ( $\Omega$ )
- $C_L$  = output load capacitance ( $\mu F$ )

### 9.3.3.1 QOD When System Power is Removed

The adjustable QOD can be used to control the power down sequencing of a system even when the system power supply is removed. When the power is removed, the input capacitor discharges at  $V_{IN}$ . Past a certain  $V_{IN}$  level, the strength of the  $R_{PD}$  is reduced. If there is still remaining charge on the output capacitor, this results in longer fall times. For further information regarding this condition, see the [Setting Fall Time for Shutdown Power Sequencing](#) section.

## 9.4 Full-Time Reverse Current Blocking

In a scenario where the device is enabled and  $V_{OUT}$  is greater than  $V_{IN}$  there is potential for reverse current to flow through the pass FET or the body diode. When the reverse current threshold ( $I_{RCB}$ ) is exceeded, the switch is disabled within  $t_{RCB}$ . The Switch remains off and block reverse current as long as the reverse voltage condition exists. After  $V_{OUT}$  has dropped below the  $V_{RCB}$  release threshold the device turns back on with slew rate control.

## 9.5 Device Functional Modes

[Table 9-2](#) describes the connection of the VOUT pin depending on the state of the ON pin as well as the various QOD pin configurations.

**Table 9-2. VOUT Connection**

ON	QOD CONFIGURATION	TPS22917 VOUT	TPS22917L VOUT
L	QOD pin connected to VOUT with $R_{QOD}$	GND (via QOD + $R_{QOD}$ )	VIN
L	QOD pin tied to VOUT directly	GND (via QOD)	VIN
L	QOD pin left open	Floating	VIN
H	QOD pin connected to VOUT with $R_{QOD}$	VIN	GND (via QOD + $R_{QOD}$ )
H	QOD pin tied to VOUT directly	VIN	GND (via QOD)
H	QOD pin left open	VIN	Floating

## 10 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 10.1 Application Information

This section highlights some of the design considerations when implementing this device in various applications.

### 10.2 Typical Application

This typical application demonstrates how the TPS22917x device can be used to power downstream modules.



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**Figure 10-1. Typical Application Schematic**

#### 10.2.1 Design Requirements

For this design example, use the values listed in [Table 10-1](#) as the design parameters:

**Table 10-1. Design Parameters**

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage ( $V_{IN}$ )	3.6 V
Load current / resistance ( $R_L$ )	1 k $\Omega$
Load capacitance ( $C_L$ )	47 $\mu$ F
Minimum fall time ( $t_F$ )	40 ms
Maximum inrush current ( $I_{RUSH}$ )	150 mA

## 10.2.2 Detailed Design Procedure

### 10.2.2.1 Limiting Inrush Current

Use Equation 5 to find the maximum slew rate value to limit inrush current for a given capacitance:

$$(\text{Slew Rate}) = I_{\text{RUSH}} \div C_L \quad (5)$$

where

- $I_{\text{INRUSH}}$  = maximum acceptable inrush current (mA)
- $C_L$  = capacitance on VOUT ( $\mu\text{F}$ )
- Slew Rate = Output Slew Rate during turn on (mV/ $\mu\text{s}$ )

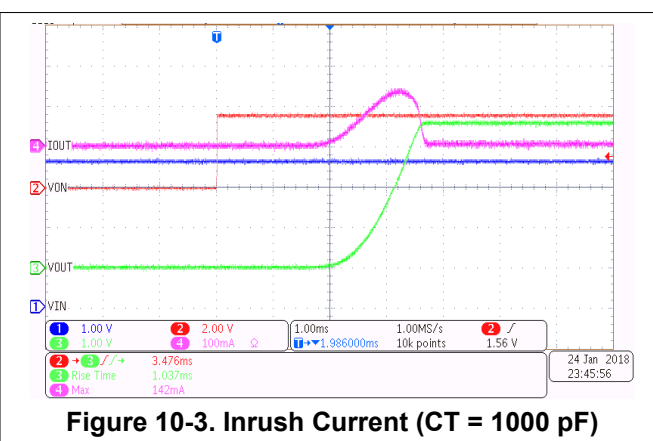
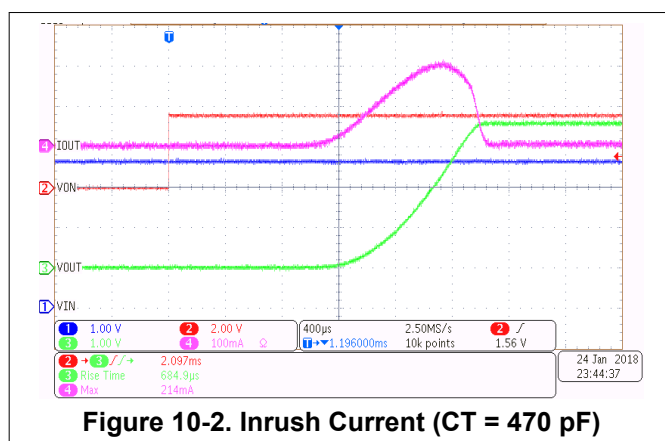
After the required slew rate shown in Equation 1 can be used to find the minimum CT capacitance

$$CT = SR_{\text{ON}} \div (\text{Slew Rate}) \quad (6)$$

$$CT = 1900 \div 3.2 = 594 \text{ pF} \quad (7)$$

To ensure an inrush current of less than 150 mA, choose a CT value greater than 594 pF. An appropriate value must be placed on such that the  $I_{\text{MAX}}$  and  $I_{\text{PLS}}$  specifications of the device are not violated.

### 10.2.2.2 Application Curves



### 10.2.2.3 Setting Fall Time for Shutdown Power Sequencing

Microcontrollers and processors often have a specific shutdown sequence in which power must be removed. Using the adjustable Quick Output Discharge function of the TPS22917x, adding a load switch to each power rail can be used to manage the power down sequencing. To determine the QOD values for each load switch, first confirm the power down order of the device you wish to power sequence. Be sure to check if there are voltage or timing margins that must be maintained during power down.

After the required fall time is determined, the maximum external discharge resistance ( $R_{\text{DIS}}$ ) value can be found using Equation 4:

$$t_{\text{FALL}} = 2.2 \times (R_{\text{DIS}} \parallel R_L) \times C_L \quad (8)$$

$$R_{\text{DIS}} = 630 \Omega \quad (9)$$

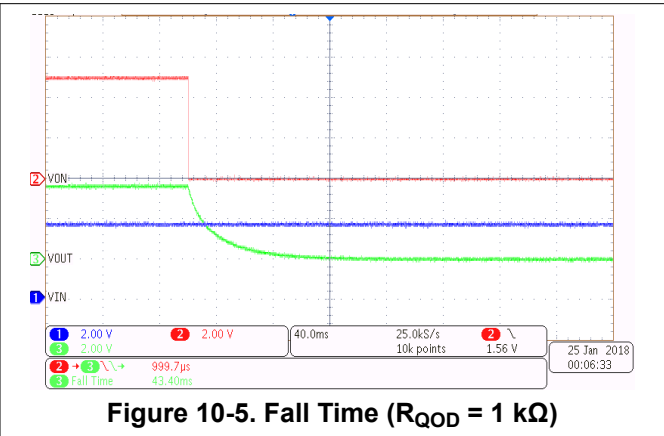
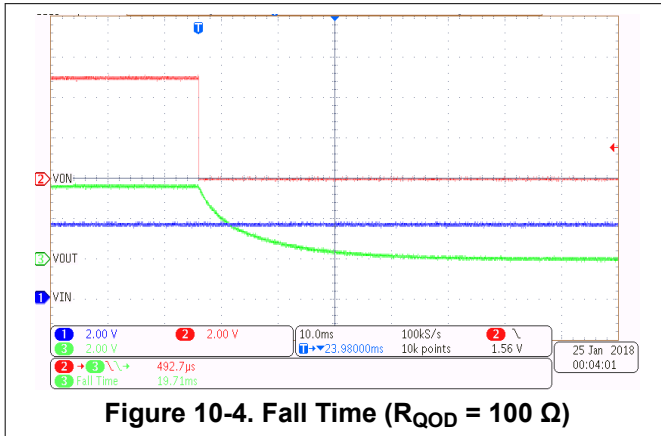
Equation 3 can then be used to calculate the  $R_{\text{QOD}}$  resistance needed to achieve a particular discharge value:

$$R_{\text{DIS}} = QOD + R_{\text{QOD}} \quad (10)$$

$$R_{\text{QOD}} = 480 \Omega \quad (11)$$

To ensure a fall time greater than, choose an  $R_{QOD}$  value greater than  $480 \Omega$ .

### 10.2.2.4 Application Curves



## 11 Power Supply Recommendations

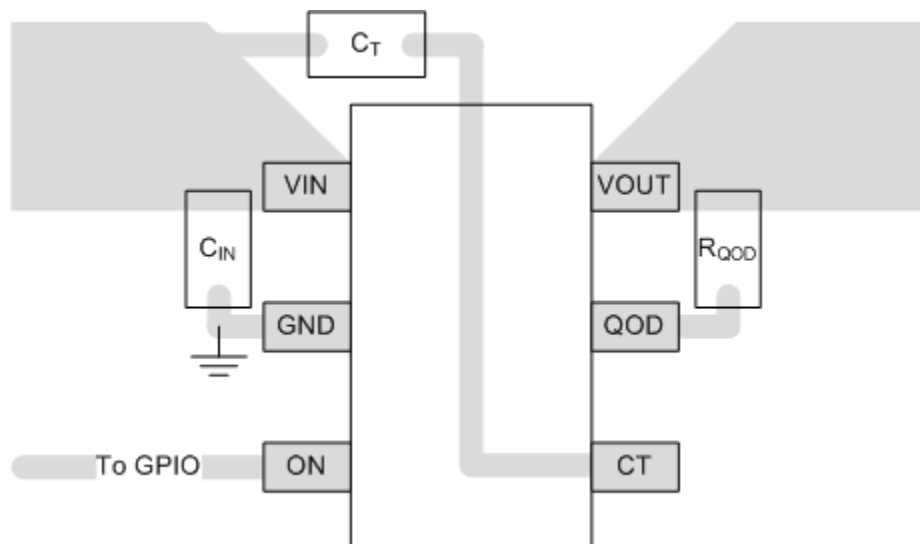
The device is designed to operate with a  $V_{IN}$  range of 1 V to 5.5 V. The  $V_{IN}$  power supply must be well regulated and placed as close to the device terminal as possible. The power supply must be able to withstand all transient load current steps. In most situations, using an input capacitance ( $C_{IN}$ ) of  $1 \mu\text{F}$  is sufficient to prevent the supply voltage from dipping when the switch is turned on. In cases where the power supply is slow to respond to a large transient current or large load current step, additional bulk capacitance can be required on the input.

## 12 Layout

### 12.1 Layout Guidelines

For best performance, all traces must be as short as possible. To be most effective, the input and output capacitors must be placed close to the device to minimize the effects that parasitic trace inductances can have on normal operation. Using wide traces for VIN, VOUT, and GND helps minimize the parasitic electrical effects.

### 12.2 Layout Example



**Figure 12-1. Recommended Board Layout**

### 12.3 Thermal Considerations

The maximum IC junction temperature must be restricted to 125°C under normal operating conditions. To calculate the maximum allowable dissipation,  $P_{D(MAX)}$  for a given output current and ambient temperature, use [Equation 12](#):

$$P_{D(MAX)} = \frac{T_{J(MAX)} - T_A}{\theta_{JA}} \quad (12)$$

where

- $P_{D(MAX)}$  = maximum allowable power dissipation
- $T_{J(MAX)}$  = maximum allowable junction temperature (125°C for the TPS22917x)
- $T_A$  = ambient temperature of the device
- $\theta_{JA}$  = junction to air thermal impedance. Refer to the [Thermal Information](#) section. This parameter is highly dependent upon board layout.

## 13 Device and Documentation Support

### 13.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](http://ti.com). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 13.2 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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### 13.3 Trademarks

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### 13.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 13.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">TPS22917DBVR</a>	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	11AF
TPS22917DBVR.A	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	11AF
TPS22917DBVRG4	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	11AF
TPS22917DBVRG4.A	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	11AF
<a href="#">TPS22917DBVT</a>	Active	Production	SOT-23 (DBV)   6	250   SMALL T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	11AF
TPS22917DBVT.A	Active	Production	SOT-23 (DBV)   6	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	11AF
<a href="#">TPS22917LDBVR</a>	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-45 to 125	2K7F
TPS22917LDBVR.A	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2K7F
TPS22917LDBVRG4	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2K7F
TPS22917LDBVRG4.A	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2K7F

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS22917DBVR	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS22917DBVRG4	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS22917DBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS22917LDBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS22917LDBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS22917LDBVRG4	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS22917DBVR	SOT-23	DBV	6	3000	208.0	191.0	35.0
TPS22917DBVRG4	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS22917DBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
TPS22917LDBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS22917LDBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS22917LDBVRG4	SOT-23	DBV	6	3000	210.0	185.0	35.0

# DBV0006A



# PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



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## NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Reference JEDEC MO-178.

# EXAMPLE BOARD LAYOUT

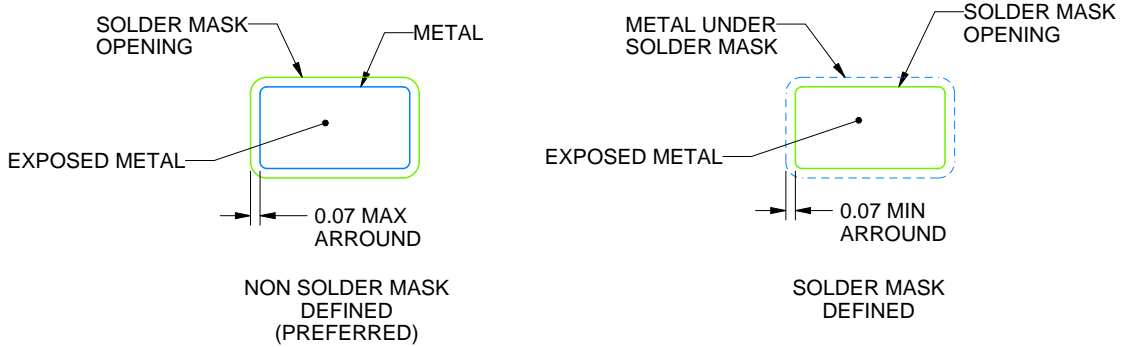
DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS

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NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

4214840/G 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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